

#### **Features**

·Freq: DC-12.0 GHz ·Insertion Loss: 0.8 dB

·Isolation: 45 dB

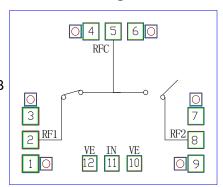
·Input Return Loss: -16 dB

·On-state output return loss: -18 dB

 $\cdot$ 50 $\Omega$  Input/ Output

·Die Size: 1.4×1.1×0.1mm<sup>3</sup>

#### **Functional Diagram**



### **General Description**

The MC1526 is a nonreflective SP4T switch which operates during DC-12.0 GHz. The typical insertion loss is 0.8dB and the isolation is 45dB. With 0V/+3.3V logic control, an external -5V power bias is required, the typical bias current is 2mA, and the switching speed is less than 50ns.

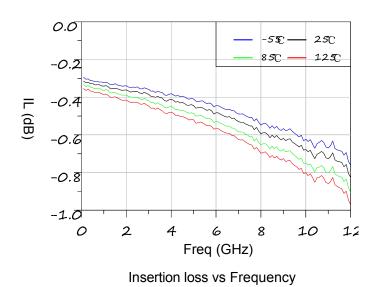
The Chip applies the on-chip metallization through-hole technology thus no need for additional grounding measures which makes it easy and convenient to use. The backside of the chip is metallized. suitable for conductive adhesive bonding or eutectic mounting process.

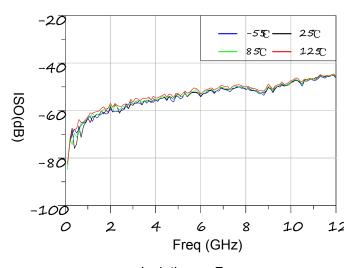
### Electrical Specifications (TA=+25°C, 50Ω system,0V/+3.3V Control (0/+5V Control Compatible))

Parameter		Min.	Тур.	Max.	Unit
Frequency Range	Freq	DC	-	12.0	GHz
Insertion Loss	IL	-	0.8	-	dB
Isolation	ISO	-	45	-	dB
Input Return Loss	IRL	-	-16	-	dB
On-state output return loss	ORL	-	-18	-	dB
Switching time	Т	-	-	50	ns
Bias current	I	-	2	-	mA

<sup>[1]</sup> The chips are 100% DC and RF tested.

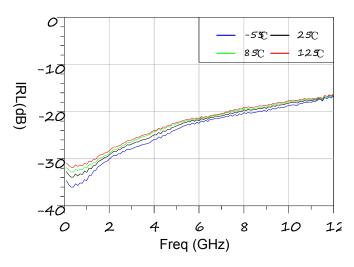
## **Typical Testing Characteristics**



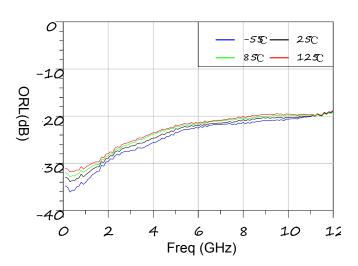


Isolation vs Frequency





Input Return Loss vs Frequency



On-state output return loss vs Frequency

#### **Absolute Maximum Ratings**

Parameter Limits	Value	
Input Power,50Ω	23dBm	
Control Voltage	0V~+5V	
Storage Temperature	-65~+150℃	
Operating Temperature	-55~+125℃	
Mounting Temperature (30s, N <sub>2</sub> Protection)	300℃	

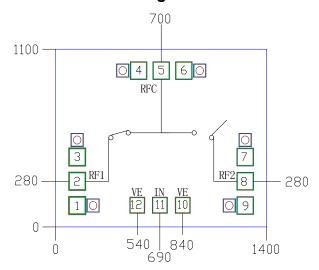
Exceeding the above conditions may cause permanent



This product is ESD(Electrostatic discharge) sensitive. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

- ·Assembling in a clean environment.
- ·Avoiding rapid temperature changes during the mounting process.
- ·Do not touch the surface or use dry/wet chemical methods to clean the surface
- $\cdot$ 2 bonding wires for input and output (in figure  $\not$ \), the bonding wires should be as short as possible.
- ·Storing in a dry, N<sub>2</sub> protection environment.

#### **Outline Drawing**



#### Notes:

- 1. Unit:µm
- 2. Back Side Metallization: Gold
- 3. Back side metal is ground
- 4. Bonding pad size: 100μm
- 5. Outline Dimensional Tolerance:±50 µm



## **Pad Descriptions**

Pad No.	Function	Description	Interface Schematic
5	RFC	RF signal input, $50\Omega$ matched, without blocking capacitor inside	-├—○RFIN
2, 8	RFOUT	RF Signal output, $50\Omega$ matched, without blocking capacitor inside	RFOUT
11	IN	DC control signal, 0V/+3.3V voltage matched	IN O
10, 12	VE	Bias voltage, these two VEs are connected internally, connect either of them while use	VE ↓ ↓
1, 3, 4, 6, 7, 9	GND	Grounding pad for probe test	ÿ GND —
Die Bottom	GND	Die bottom must be connected to RF/DC ground	Ģ GND <u>=</u>

**Control Voltage Range** 

	Control voltage rtail	<u>                                       </u>		
	Тур.	Control Voltage Range		
0V		0V~+0.5V		
	+3.3V	+3V~+5V		

# **Control Logic**

Power Voltage	Control Input	On-off state		
VE	IN	RF1	RF2	
-5V	0V	ON	OFF	
-5V	+3.3V	OFF	ON	

# **Assembly Diagram**

